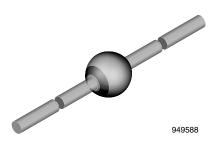
Vishay Semiconductors

# **Ultra-Fast Avalanche Sinterglass Diode**



#### **FEATURES**

- · Glass passivated
- · Hermetically sealed axial leaded glass envelope
- Low reverse current
- High reverse voltage
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition



RoHS

COMPLIANT HALOGEN FREE

### **MECHANICAL DATA**

Case: SOD-64

Terminals: plated axial leads, solderable per MIL-STD-750,

method 2026

Polarity: color band denotes cathode end

**Mounting position:** any **Weight:** approx. 858 mg

### **APPLICATIONS**

- Switched mode power supplies
- High-frequency inverter circuits

PARTS TABLE				
PART	TYPE DIFFERENTIATION	PACKAGE		
SF5400	V <sub>R</sub> = 50 V; I <sub>FAV</sub> = 3 A	SOD-64		
SF5401	V <sub>R</sub> = 100 V; I <sub>FAV</sub> = 3 A	SOD-64		
SF5402	V <sub>R</sub> = 200 V; I <sub>FAV</sub> = 3 A	SOD-64		
SF5403	V <sub>R</sub> = 300 V; I <sub>FAV</sub> = 3 A	SOD-64		
SF5404	V <sub>R</sub> = 400 V; I <sub>FAV</sub> = 3 A	SOD-64		
SF5405	V <sub>R</sub> = 500 V; I <sub>FAV</sub> = 3 A	SOD-64		
SF5406	V <sub>R</sub> = 600 V; I <sub>FAV</sub> = 3 A	SOD-64		
SF5407	V <sub>R</sub> = 800 V; I <sub>FAV</sub> = 3 A	SOD-64		
SF5408	V <sub>R</sub> = 1000 V; I <sub>FAV</sub> = 3 A	SOD-64		

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
Reverse voltage = repetitive peak reverse voltage	See electrical characteristics	SF5400	$V_R = V_{RRM}$	50	V	
		SF5401	$V_R = V_{RRM}$	100	V	
		SF5402	$V_R = V_{RRM}$	200	V	
		SF5403	$V_R = V_{RRM}$	300	V	
		SF5404	$V_R = V_{RRM}$	400	V	
Toverse vollage		SF5405	$V_R = V_{RRM}$	500	V	
		SF5406	$V_R = V_{RRM}$	600	V	
		SF5407	$V_R = V_{RRM}$	800	V	
		SF5408	$V_R = V_{RRM}$	1000	V	
Peak forward surge current	t <sub>p</sub> = 10 ms, half sine wave		I <sub>FSM</sub>	150	Α	
Average forward current			I <sub>FAV</sub>	3	Α	
Junction and storage temperature range			$T_j = T_{stg}$	- 55 to + 175	°C	
Non repetitive reverse avalanche energy	I <sub>(BR)R</sub> = 0.4 A		E <sub>R</sub>	10	mJ	

Vishay Semiconductors

Ultra-Fast Avalanche Sinterglass Diode



<b>MAXIMUM THERMAL RESISTANCE</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	BOL VALUE UN		
Junction ambient	Lead length I = 10 mm, T <sub>L</sub> = constant	$R_{thJA}$	25	K/W	
	On PC board with spacing 25 mm	$R_{thJA}$	70	K/W	

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 3 A	SF5400	$V_{F}$	-	-	1.1	V
		SF5401	V <sub>F</sub>	-	-	1.1	V
		SF5402	V <sub>F</sub>	-	-	1.1	V
		SF5403	$V_{F}$	-	-	1.1	V
		SF5404	$V_{F}$	-	-	1.1	V
		SF5405	$V_{F}$	-	-	1.7	V
		SF5406	$V_{F}$	-	=.	1.7	V
		SF5407	$V_{F}$	-	=.	1.7	V
Reverse current	$V_R = V_{RRM}$		I <sub>R</sub>	-	-	5	μA
	$V_R = V_{RRM}$ , $T_j = 125$ °C		I <sub>R</sub>	-	-	50	μA
	I <sub>R</sub> = 100 μA	SF5400	V(BR)R	60	-	-	V
		SF5401	V(BR)R	110	=.	-	V
		SF5402	V(BR)R	220	-	-	V
		SF5403	V(BR)R	330	=.	-	V
Reverse breakdown voltage		SF5404	V(BR)R	440	-	-	V
		SF5405	V(BR)R	550	-	-	V
		SF5406	V(BR)R	660	-	-	V
		SF5407	V(BR)R	880	-	-	V
		SF5408	V(BR)R	1100	=.	-	V
Reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, i <sub>R</sub> = 0.25 A	SF5400	t <sub>rr</sub>	-	-	50	ns
		SF5401	t <sub>rr</sub>	-	-	50	ns
		SF5402	t <sub>rr</sub>	-	-	50	ns
		SF5403	t <sub>rr</sub>	-	=	50	ns
		SF5404	t <sub>rr</sub>	-	=	50	ns
		SF5405	t <sub>rr</sub>	-	-	75	ns
		SF5406	t <sub>rr</sub>	-	=	75	ns
		SF5407	t <sub>rr</sub>	-	-	75	ns

## TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

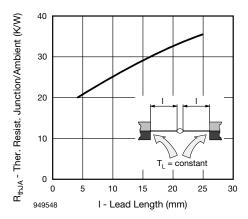


Fig. 1 - Max. Thermal Resistance vs. Lead Length

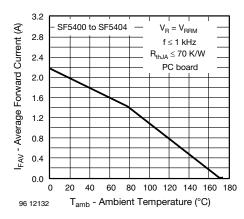


Fig. 2 - Max. Average Forward Current vs. Ambient Temperature



# Ultra-Fast Avalanche Sinterglass Vishay Semiconductors Diode

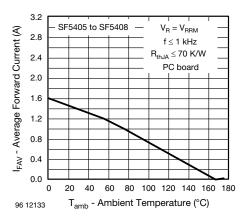


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

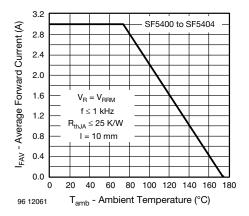


Fig. 4 - Max. Average Forward Current vs. Ambient Temperature

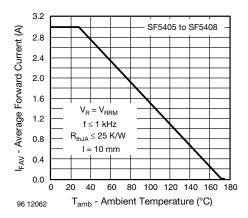


Fig. 5 - Max. Average Forward Current vs. Ambient Temperature

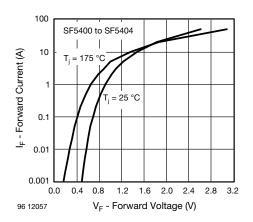


Fig. 6 - Max. Forward Current vs. Forward Voltage

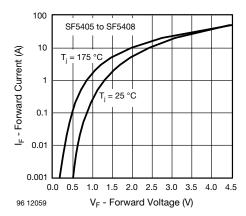


Fig. 7 - Max. Forward Current vs. Forward Voltage

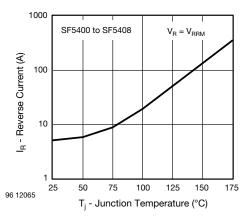


Fig. 8 - Max. Reverse Current vs. Junction Temperature

# Vishay Semiconductors

## Ultra-Fast Avalanche Sinterglass Diode



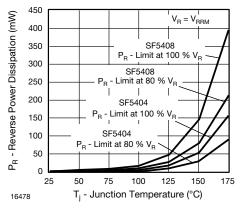


Fig. 9 - Max. Reverse Power Dissipation vs. Junction Temperature

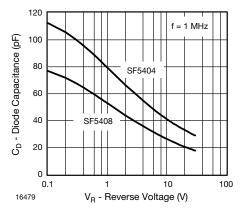
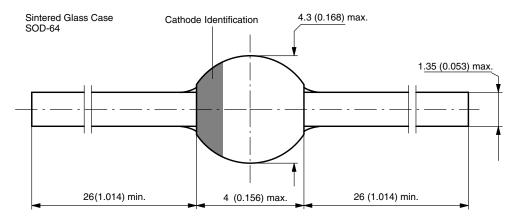


Fig. 10 - Diode Capacitance vs. Reverse Voltage

### PACKAGE DIMENSIONS in millimeters (inches): SOD-64



Document-No.: 6.563-5006.4-4 Rev. 3 - Date: 09.February.2005

94 9587

# **Legal Disclaimer Notice**



Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1